

September 1983 Revised January 2005

# MM74HC32 Quad 2-Input OR Gate

#### **General Description**

The MM74HC32 OR gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. All gates have buffered outputs providing high noise immunity and the ability to drive 10 LS-TTL loads. The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to  $V_{\rm CC}$  and ground.

#### **Features**

- Typical propagation delay: 10 ns
- Wide power supply range: 2-6V
- Low quiescent current: 20 µA maximum (74HC Series)
- Low input current: 1 µA maximum
- Fanout of 10 LS-TTL loads

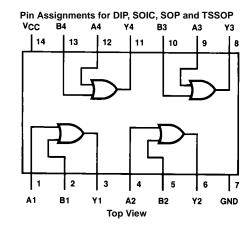
#### **Ordering Code:**

Order Number	Package Number	Package Description		
MM74HC32M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow		
MM74HC32MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow		
MM74HC32SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide		
MM74HC32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide		
MM74HC32MTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide		
MM74HC32N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide		
MM74HC32N_NL	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide		

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Pb-Free package per JEDEC J-STD-020B.

#### **Connection Diagram**



#### **Logic Diagram**

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DS005132

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## **Absolute Maximum Ratings**(Note 1)

(Note 2)

Supply Voltage (V <sub>CC</sub> )	-0.5  to + 7.0 V
DC Input Voltage (V <sub>IN</sub> )	$-1.5$ to $V_{CC} + 1.5V$
DC Output Voltage (V <sub>OUT</sub> )	$-0.5$ to $V_{CC} + 0.5V$
Clamp Diode Current (I <sub>IK</sub> , I <sub>OK</sub> )	±20 mA
DC Output Current, per pin (I <sub>OUT</sub> )	±25 mA
DC $V_{CC}$ or GND Current, per pin ( $I_{CC}$ )	±50 mA
Storage Temperature Range (T <sub>STG</sub> )	-65°C to +150°C
Power Dissipation (P <sub>D</sub> )	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T <sub>L</sub> )	
(Soldering 10 seconds)	260°C

# Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V <sub>CC</sub> )	2	6	V
DC Input or Output Voltage	0	$V_{CC}$	V
$(V_{IN}, V_{OUT})$			
Operating Temperature Range (T <sub>A</sub> )	-40	+85	°C
Input Rise or Fall Times			
$(t_r, t_f) V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

#### DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> = 25°C		T <sub>A</sub> = -40 to 85°C	Units
			*CC	Тур	Gu	aranteed Limits	Units
V <sub>IH</sub>	Minimum HIGH Level		2.0V		1.5	1.5	V
	Input Voltage		4.5V		3.15	3.15	V
			6.0V		4.2	4.2	V
V <sub>IL</sub>	Maximum LOW Level		2.0V		0.5	0.5	V
	Input Voltage		4.5V		1.35	1.35	V
			6.0V		1.8	1.8	V
V <sub>OH</sub>	Minimum HIGH Level	$V_{IN} = V_{IH}$ or $V_{IL}$					
	Output Voltage	I <sub>OUT</sub>   ≤ 20 μA	2.0V	2.0	1.9	1.9	V
			4.5V	4.5	4.4	4.4	V
			6.0V	6.0	5.9	5.9	V
		$V_{IN} = V_{IH}$ or $V_{IL}$					
		I <sub>OUT</sub>   ≤ 4.0 mA	4.5V	4.7	3.98	3.84	V
		I <sub>OUT</sub>   ≤ 5.2 mA	6.0V	5.2	5.48	5.34	V
V <sub>OL</sub>	Maximum LOW Level	$V_{IN} = V_{IL}$					
	Output Voltage	$ I_{OUT}  \le 20 \mu A$	2.0V	0	0.1	0.1	V
			4.5V	0	0.1	0.1	V
			6.0V	0	0.1	0.1	V
		$V_{IN} = V_{IL}$					
		I <sub>OUT</sub>   ≤ 4.0 mA	4.5V	0.2	0.26	0.33	V
		$ I_{OUT}  \le 5.2 \text{ mA}$	6.0V	0.2	0.26	0.33	V
I <sub>IN</sub>	Maximum Input	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	μΑ
	Current						
I <sub>CC</sub>	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND	6.0V		2.0	20	μΑ
	Supply Current	$I_{OUT} = 0 \mu A$					

Note 4: For a power supply of 5V  $\pm$ 10% the worst case output voltages (V<sub>OH</sub>, and V<sub>OL</sub>) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub> = 5.5V and 4.5V respectively. (The V<sub>IH</sub> value at 5.5V is 3.85V.) The worst case leakage current (I<sub>IN</sub>, I<sub>CC</sub>, and I<sub>OZ</sub>) occur for CMOS at the higher voltage and so the 6.0V values should be used.

#### **AC Electrical Characteristics**

 $V_{CC} = 5V$ ,  $T_A = 25^{\circ}C$ ,  $C_L = 15$  pF,  $t_r = t_f = 6$  ns

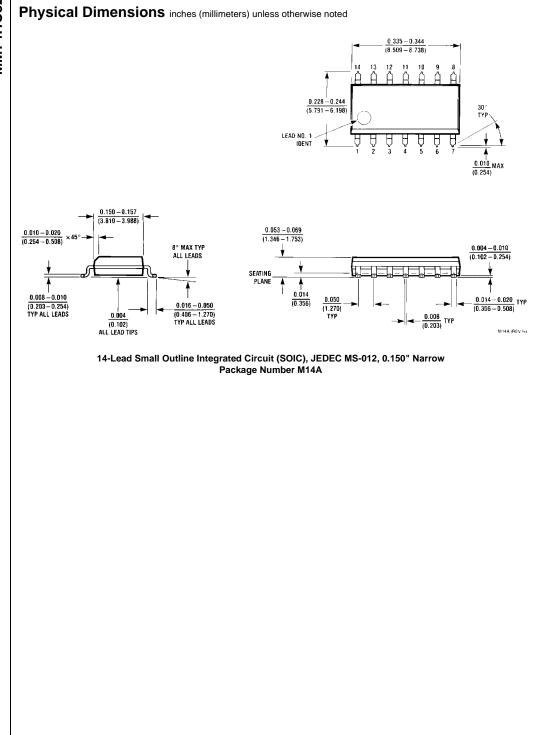
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation		10	18	ns
	Delay				

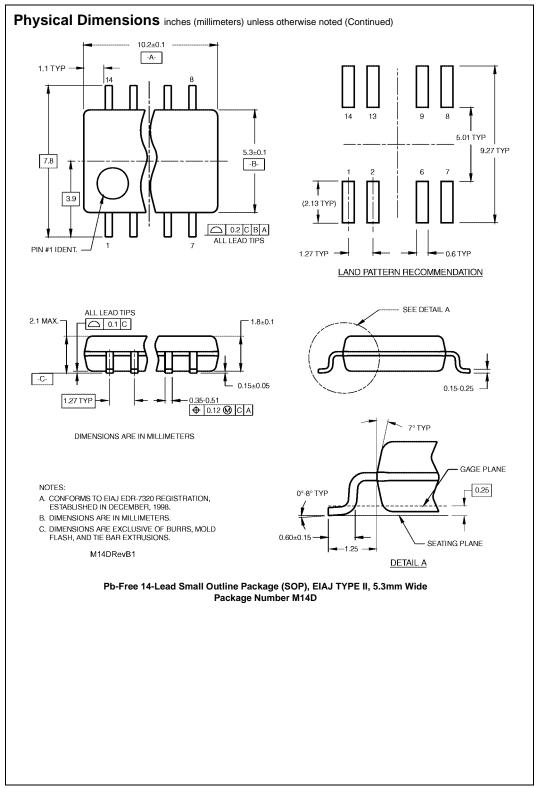
#### **AC Electrical Characteristics**

 $V_{CC} = 2.0 V$  to 6.0V,  $C_L = 50$  pF,  $t_r = t_f = 6$  ns (unless otherwise specified)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> = 25°C		T <sub>A</sub> = -40 to 85°C	Units
		Conditions	*CC	Тур	Guar	anteed Limits	Ointo
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation		2.0V	30	100	125	ns
	Delay		4.5V	12	20	25	ns
			6.0V	9	17	21	ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Rise		2.0V	30	75	95	ns
	and Fall Time		4.5V	8	15	19	ns
			6.0V	7	13	16	ns
C <sub>PD</sub>	Power Dissipation	(per gate)		50			pF
	Capacitance (Note 5)						
C <sub>IN</sub>	Maximum Input			5	10	10	pF
	Capacitance						

Note 5:  $C_{PD}$  determines the no load dynamic power consumption,  $P_D = C_{PD} \ V_{CC}^2 f + I_{CC} \ V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$ .

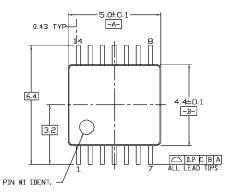


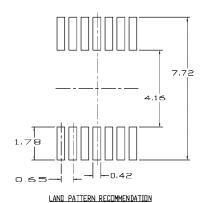


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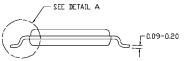
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### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





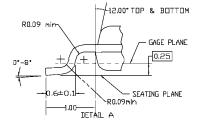
ALL LEAD TIPS  $0.90^{+0.15}_{-0.10}$ L2 MAX -C-0.10±0.05 



#### NOTES:

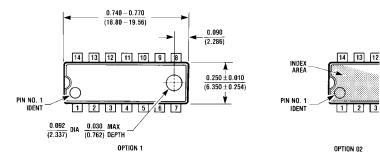
- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION ABUREF NOTE 6, DATED 7/93
- B. DIMENSIONS ARE IN MILLIMETERS
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1982

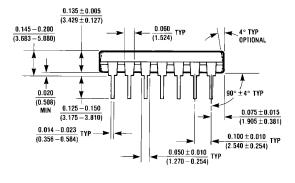
MTC14revD

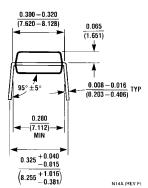


14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)







14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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